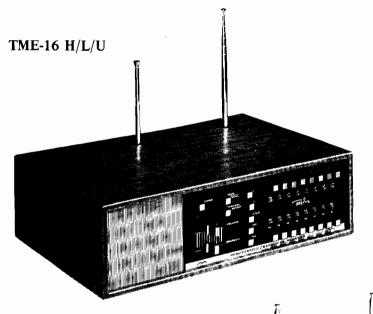
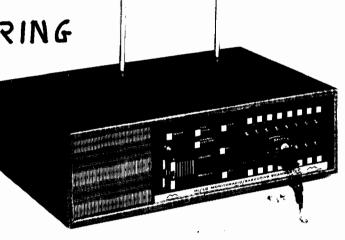


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TME-16 H/L

MONITORADIO RECEIVER

7707 RECORDS STREET INDIANAPOLIS, INDIANA 46226

PRINTED IN U.S.A.

PRICE \$5.00 SM-10-324-1

MONITORADIO RECEIVERS

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SECTION 1 SPECIFICATIONS AND CIRCUIT DESCRIPTION

1-1 SPECIFICATIONS (SUBJECT TO CHANGE WITHOUT NOTICE)

RECEIVER-MODEL TME-16H/L/U

Frequency Range Low Band; 30-50 MHz High Band; 150-174 MHz UHF Band; 450-470 MHz
Antenna Impedance
Channels
Sensitivity (at tune-up)Low Band; $0.5\mu v$ (max.)
High Band; 0.6μν (max.)
UHF Band; $0.7\mu v$ (max.)
Frequency Separation
Low Band
Model 8 H/LL/U33-39 MHz
Model 8 H/LM/U37-43 MHz
Model 8 H/LH/U41-47 MHz
High Band 6 DB Bandwidth; 8 MHz
10 DB Bandwidth; 12 MHz
UHF Band 6 DB Bandwidth; 8 MHz
10 DB Bandwidth; 12 MHz
, ,
Selectivity (I.F.) 6 DB Down; ±7 KHz (min.)
50 DB Down; ±18 KHz (max.)
Spurious Rejection(excluding Primary Image)50 DB
AFC Range (UHF Board Only)Approx. ±6 KHz
Modulation Acceptance
Intermediate Frequencies1st I.F10.7 MHz
2nd I.F455 KHz
2nd I.F455 KHz
2nd I.F455 KHz Squelch System
$\begin{tabular}{lllllllllllllllllllllllllllllllllll$
2nd I.F455 KHz Squelch System
$\begin{tabular}{lllllllllllllllllllllllllllllllllll$
2nd I.F455 KHz Squelch System'Noise Operated" Audio Output (3.2 Ω Speaker)3 Watts @ 10%, or less, distortion; 5 Watts, maximum RECEIVER-MODEL TME-16H/L
2nd I.F455 KHz Squelch System
2nd I.F455 KHz Squelch System
2nd I.F455 KHz Squelch System
2nd I.F455 KHz Squelch System
2nd I.F455 KHz Squelch System 'Noise Operated' Audio Output (3.2 Ω Speaker) 3 Watts @ 10%, or less, distortion; 5 Watts, maximum RECEIVER-MODEL TME-16H/L Frequency Range Low Band 30-50 MHz High Band; 150-174 MHz Antenna Impedance 50 Ohms Channels 50 Ohms Channels 16, Crystal Controlled Sensitivity (at tune-up) Low Band; 0.5μν (max.) High Band; 0.6μν (max.) Frequency Separation Frequency Separation
2nd I.F455 KHz Squelch System 'Noise Operated' Audio Output (3.2 Ω Speaker) 3 Watts @ 10%, or less, distortion; 5 Watts, maximum RECEIVER-MODEL TME-16H/L Frequency Range Low Band 30-50 MHz High Band; 150-174 MHz Antenna Impedance 50 Ohms Channels 50 Ohms Channels 16, Crystal Controlled Sensitivity (at tune-up) Low Band; 0.5μν (max.) High Band; 0.6μν (max.) Frequency Separation Low Band
2nd I.F455 KHz Squelch System 'Noise Operated' Audio Output (3.2 Ω Speaker) 3 Watts @ 10%, or less, distortion; 5 Watts, maximum RECEIVER-MODEL TME-16H/L Frequency Range Low Band 30-50 MHz High Band; 150-174 MHz Antenna Impedance 50 Ohms Channels 50 Ohms Channels 16, Crystal Controlled Sensitivity (at tune-up) Low Band; 0.5μν (max.) High Band; 0.6μν (max.) Frequency Separation Low Band 6 MHz "200" Series RF Board 40-47 MHz
2nd I.F455 KHz Squelch System
2nd I.F455 KHz Squelch System 'Noise Operated' Audio Output (3.2 Ω Speaker) 3 Watts @ 10%, or less, distortion; 5 Watts, maximum RECEIVER-MODEL TME-16H/L Frequency Range Low Band 30-50 MHz High Band; 150-174 MHz Antenna Impedance 50 Ohms Channels 50 Ohms Channels 16, Crystal Controlled Sensitivity (at tune-up) Low Band; 0.5μν (max.) High Band; 0.6μν (max.) Frequency Separation Low Band 6 MHz "200" Series RF Board 40-47 MHz
2nd I.F455 KHz
2nd I.F455 KHz Squelch System 'Noise Operated' Audio Output (3.2 Ω Speaker) 3 Watts @ 10%, or less, distortion; 5 Watts, maximum RECEIVER-MODEL TME-16H/L Frequency Range Low Band 30-50 MHz High Band; 150-174 MHz High Band; 150-174 MHz Antenna Impedance 50 Ohms Channels 50 Ohms Channels 16, Crystal Controlled Sensitivity (at tune-up) Low Band; 0.5μν (max.) High Band; 0.6μν (max.) Frequency Separation Low Band 6 MHz "200" Series RF Board 40-47 MHz "300" Series RF Board 33-40 MHz High Band 6 DB Bandwidth; 8 MHz 10 DB Bandwidth; 12 MHz 10 DB Bandwidth; 1
2nd I.F455 KHz
2nd I.F455 KHz Squelch System 'Noise Operated' Audio Output (3.2 Ω Speaker) 3 Watts @ 10%, or less, distortion; 5 Watts, maximum RECEIVER-MODEL TME-16H/L Frequency Range Low Band 30-50 MHz High Band; 150-174 MHz High Band; 150-174 MHz Antenna Impedance 50 Ohms Channels 50 Ohms Channels 16, Crystal Controlled Sensitivity (at tune-up) Low Band; 0.5μν (max.) High Band; 0.6μν (max.) Frequency Separation Low Band 6 MHz "200" Series RF Board 40-47 MHz "300" Series RF Board 33-40 MHz High Band 6 DB Bandwidth; 8 MHz 10 DB Bandwidth; 12 MHz 10 DB Bandwidth; 1

Modulation Acceptance	
Intermediate Frequencies	
2nd I.F455 KH	
Squelch System'Noise Operated	•
Audio Output (3.2 Ω Speaker) 3 Watts @ 10%, or less	
distortion; 5 Watts, maximum	n
SCANNER	
Scan RateApprox. 15 channels per sec	
Scan Delay	•
Scan DelayApprox. 1/2 sec	•
POWER	
Voltage Requirement	
60 Hz., 17 Watts Max	
13.8 VDC (±10%)	
Current Requirements @ 13.8 VD	3
Receiver (Squelched)	
Receiver (Max. Audio Output)800 MA	
Fuse Size1.5 Amp., 3A	3
SEMICONDUCTORS	
Pagainen Castia	
Receiver Section Integrated Circuits	
Silicon Transistors	
Field Effect Transistors	
Diode (Total) Model TME-16H/L; 20	
Model TME-16H/L/U; 2	
Zener Diodes	i
Rectifier Diodes	2
Varactor DiodeModel TME-16H/L/U only;	Ĺ
Scanner Section	
Integrated Circuits	3
Silicon Transistors	
Diodes (Total)Model TME-16H/L/U; 3	1
Model TME-16H/L; 39)
Zener Diodes	2
GENERAL	
Front Panel Size 7/8" x 13	1
Depth (Including Knobs and Rear Panel Connectors) 9 1/2	
Antenna Connector	
Power Connector4-pin, polarized	
Speaker Size4 inch. square	

1-2 CRYSTAL SPECIFICATIONS

Minature plug-in crystals are utilized in the receiver. Because of the high accuracy (close tolerances) required, Shepherd Industries' crystals are recommended. If the crystals are ordered from Regency, it is only necessary to specify Part No. 301-532 for high band crystals and the desired

receive frequency, of Part No. 301--542 for low band crystals and the desired receive frequency, or Part No. 301--603 for UHF crystals and the desired receive frequency.

If desired, the crystals may be purchased from other manufacturers. The following specifications must be included in the order:

High Band Crystal:

a. Crystal frequency, determined as follows: Crystal frequency = <u>channel frequency-10.7 MHz</u>

EXAMPLE:

Crystal frequency = 155.55 MHz-10.7 MHz = 144.85 MHz = 48.2833 MHz = 3

- b. Frequency Tolerance of .001%
- c. 3rd Overtone
- d. Series resonance minus 450 Hz
- e. Maximum equivalent series resistance of 35 ohms
- f. Drive level of 2 MW
- g. Holder: HC-25/u

Low Band Crystal:

a. Crystal frequency, determined as follows:
 Crystal frequency = channel frequency + 10.7 MHz

EXAMPLE:

Crystal frequency = 39.5 MHz + 10.7 MHz = 50.2 MHz

- b. Frequency Tolerance of .001%
- c. 3rd Overtone
- d. Series resonance minus 450 Hz
- e. Maximum equivalent series resistance of 35 ohms
- f. Drive level of 2 MW
- g. Holder: HC-25/u

UHF Band Crystal:

a. Crystal Frequency = Receive Frequency-10.7 MHz

EXAMPLE:

Crystal Frequency = 458.000 MHz-10.700 MHz

Crystal Frequency = 49.70000 MHz

- b. Frequency Tolerance of .001%
- c. 3rd overtone
- d. Parallel resonance-18pf load capacity
- e. Maximum equivalent series resistance of 35 ohms
- f. Drive level of 2 MW
- g. Holder: HC-25/u

1-3 CRYSTAL INSTALLATION AND BAND PROGRAMMING

Prior to installing a crystal, the receiver will have to be partially pulled out of its cabinet. First, remove the telescopic antennas if they are installed. Second, remove the two knobs (volume and squelch). Third, remove the rear panel (cover) by removing the four mounting screws. Fourth, remove the four rubber feet by unscrewing each one. The receiver may then be slid rearward from the cabinet until the crystal socket pins are accessible.

Insert the crystal in the proper socket pins as indicated on the Crystal Location Diagram 3-12. The sockets are numbered, in pairs, corresponding to the channel number on the front panel.

For high and low band crystals inserted into the 301-563 High/Low RF Board, band programming will have to be performed. If the crystal inserted is for the High Band (148-174 MHz), place the proper color-coded wire and socket onto the proper High Band pin; if the crystal is for the Low Band (30-50 MHz), place the proper wire and socket onto the proper Low Band pin. Pictorial B illustrates how the band selection wires are properly connected. Pictorial C shows an example of a partially programmed board. See Diagram 3-13.

NOTE: If a particular channel is not used in the High/Low Board (in other words, there is no crystal installed for that channel), the band selection wire must still be connected to either a High band pin or to a Low band pin. Thus, for proper scanner operation, all of band selection wires MUST be connected, even though not all channels are used.

After the crystals are installed and any necessary band programming changes are completed, carefully slide the unit back into the cabinet. Screw the four feet back into place and replace the rear panel. Push the volume and squelch knobs back on their shafts and the unit is again ready for operation.

1-4 RF BOARD

Q201 is a low band RF amplifier with broad-band tuned circuits in its input and output circuitry. The output of the RF amplifier is coupled to the input of the low band mixer, Q203.

Q202 is a high band RF amplifier with broad-band circuits in its input

and output circuitry. The output of the RF amplifier is coupled to the input of the high band mixer, Q204.

The first L.O. (local oscillator), Q207, uses third overtone crystals and operates on all channels, whether high or low. For low band signals the fundamental frequency of the crystal is taken off the emitter of Q207 for injection. For high band signals, the third harmonic of the crystal is coupled off the collector of Q207 for oscillator injection. The radio is switched between high and low band by transistors Q205 and Q206. When Q205 conducts, operating bias is applied to the low band RF amplifier and mixer. When Q206 conducts, operating bias is applied to the high band RF amplifier and mixer. Each channel then becomes either high band or low band depending on which RF amplifier and mixer are switched on by Q205 or Q206. Conduction of Q205 and Q206 are determined by the program board. If the lead for a particular channel is connected to a high band pin, the high band RF amplifier and mixer are turned on, if the lead is connected to a low band pin, the low band RF amplifier and mixer are turned on when the radio scans that particular channel.

A crystal is electrically connected to the oscillator circuit when its associated diode is forward biased. Until the scanner reaches that particular channel, the diode is back biased and prevents the oscillator from operating on the crystal's frequency. When the respective channel is reached, the scanner's output line provides a low resistance path to ground, which turns the diode on (forward biases it) and effectively connects the crystal into the oscillator circuit.

The output frequency from either mixer, Q203 or Q204, is tuned to 10.7 MHz by T201. The output is linked-coupled to T101, the IF input tuned circuit.

On Model TME-16H/L, the "300" series RF board is identical to the previous description except for one being a "200" series board and the other a "300" series board.

For the "300" series RF board for Model TME-16H/L/U, Q301 is a Field Effect RF transistor used in the common gate configuration. Q301 has broad band tuned circuits in its input and output circuitry. The output from the RF amplifier is coupled to the mixer transistor Q302.

The first L.O. (local oscillator), Q303, uses third overtone crystals. The output frequency from the oscillator, (3 times the crystal frequency), is coupled to the base of Q307. Q307 is a tripler which multiplies the oscillator output by 3 for use as the ultimate injection frequency (9 times the crystal frequency). The output of Q307 is coupled to the mixer transistor, Q302.

A crystal is electrically connected to the oscillator circuit when its associated diode is forward biased. Until the scanner reaches that particular channel, the diode is back biased and prevents the oscillator from operating on the crystal's frequency. When the respective channel is reached, the scanner's output line provides a low resistance path to ground, which turns the diode on (forward biases it) and effectively connects the crystal into the oscillator circuit.

The automatic frequency control circuit (AFC) consists of Q304, Q305, Q306 and CR309. Q305 and Q306 form a differential amplifier. The voltage at pin 1 of IC 102 is determined by the amount the signal is off frequency; this is called an error voltage. The error voltage is amplified by Q304 and applied to CR309. CR309 is a voltage dependent capacitor, or varactor, in the oscillator circuit. When the voltage applied to CR309 changes, the frequency of the oscillator is changed.

The second L.O. frequency is normally 10.245 MHz. In cases where interference is encountered from a signal approximately 910 KHz from the desired frequency, the second L.O. may be changed to 11.155 MHz. If the second L.O. is 10.245 MHz, the error voltage is taken from the collector of Q306. If the second L.O. has been changed to 11.155 MHz, the error voltage is taken from the collector of Q305. The correct combination can be determined by checking the frequency stamped on the second L.O. crystal, (Y101).

1-5 IF-AUDIO BOARD

The IF input circuitry consists of T101 and Q101, used as an IF amplifier. The output of this amplifier is fed to an integrated circuit, IC 101, which contains another amplifier for 10.7 MHz, the second mixer circuitry and the second L.O. circuitry, normally operating at 10.245 MHz. In some locations where a strong Image signal has been encountered, this oscillator's frequency is moved to 11.155 MHz. (The crystal frequency is stamped on the top of the crystal).

The 455 KHz output of IC 101 (terminal 5) is coupled through a tuned circuit to the input of the ceramic filter, CF-1. CF-1 is a narrow-band filter centered at 455 KHz. The excellent band-pass characteristics of CF-1 provide for very good adjacent channel rejection. The output of CF-1 is coupled through another tuned circuit to the input of integrated circuit IC 102. IC 102 is a series of amplifiers providing approximately 60 DB gain at 455 KHz. Also included in IC 102 is the limiting circuitry and a quadrature detector circuit. L103, connected between terminals 2 and 12 of IC 102, is adjustable quadrature coil.

The audio output from IC 102 (terminal 1) is coupled to the input of the audio amplifier circuit and to the input of the noise-operated squelch circuit.

Transistor Q102 is an amplifier whose frequency response extends from approximately 5 KHz to 25 KHz. Q102 amplifies the "noise" occuring in this frequency range. The noise is coupled to the base of Q103. Q103 is used as a detector which rectifies the amplified noise and produces DC voltage at its collector. When the DC voltage at the collector of Q103 is positive and of sufficient value to provide base bias for Q104, Q104 turns on and provides a short circuit to the squelch tail circuitry which provides bias to Q105. This action turns off Q105 and the audio output from the receiver is squelched (muted). When a signal (carrier) arrived, the output from the detector (Q103) is reduced to the point where the DC voltage at the base of Q104 is no longer sufficient to cause Q104 to conduct.

At this time, Q105 is allowed to conduct normally and the audio output of the unit is heard. With the audio pre-amplifier (Q105) operating normally, audio is applied through the volume control to the base of the audio amplifier, Q106. Q106 supplies a signal to the audio driver transistors, Q107 and Q108. The output transistors, Q109 and Q110, form a quasi-complementary, transformerless stage capable of delivering 5 watts to the speaker.

1-6 SCANNER BOARD

The squelch tail circuit consists of R418, CR413, C406 and R419. This circuit is used to keep the squelch circuit open for a short time after the station signal goes off. The purpose of the squelch tail circuit is to prevent the squelch circuits from chopping very weak signals, especially mobile signals. The timing of the squelch tail can be changed by changing the value of C406. Removing C406 from the circuit will remove the squelch tail completely.

Three basic functional circuits make up the Scanner system. They are the lamp gates, the registers, and a multi-speed clock. The clock circuitry also includes a stop-start circuit in addition to generating pulses.

The lamp gates, IC 401, IC 402, IC 501 and IC 502, are switched on or off by the outputs of the registers. When a gate is switched on, its respective output goes to a low voltage, providing essentially a ground path for the lamp and diode switching circuitry. Thus, the channel's lamp is lighted and its associated crystal is switched into the first local oscillator's circuit.

The registers, IC 403, IC 404, IC 503 and IC 504, convert the repetitive clock pulses into an electronic sequencing or stepping action. Each register has four output lines and all sixteen of these lines are sequenced through a low to high voltage state. Only one output is "high" at any one time. The high voltage switches on the associated gate, which activates the lamp and crystal. Each output is connected, through a diode, to an inverter-amplifier (Q401) which feeds the output pulses back to the input of the first register (IC 403). Thus, the registers are utilized in a ring or recirculating counter configuration.

The clock's primary function is to generate the pulses required by the registers. A unijunction oscillator stage (Q406) followed by a pulse amplifier (Q407) and a clock line driver (Q408) form the basic clock circuitry. There are three clock speeds (repetition rates) that are available and they are FAST, NORMAL and SLOW. Each speed is automatically selected by the scanner system for its various modes of operation.

The FAST speed (approximately 1200 Hz) is the rate the system operates at when it scans an inactive channel. In other words, if all of the channel programming buttons were in the "out" position, the scanner would actually be sequencing each channel at this extreme speed. Of course, this rate greatly exceeds the amount of time it takes for the receiver to respond to a proper signal (carrier). The FAST rate is determined by the R-C network of R 412 and C405.

The NORMAL scan rate is approximately 15 Hz and it is determined by R412, C404 and C405. C404 is essentially placed in parallel with C405 whenever Q405 is con-

ducting. When the scanner reaches an active channel (programming button for that channel is pushed in), a pulse from the register's activate output line turns on Q402 which cuts off Q 403. When Q403 is cut off (not conducting), Q405 is turned on and the clock runs at a slow enough rate for the scanner to respond to a proper signal.

The SLOW clock speed occurs when the scanner is operating in the manual channel selection mode. Pushing the SCAN-MANUAL button to the out position forces the scanner to stop. In addition, it connects another capacitor, C403, in parallel with C404. Holding the CHANNEL SELECTOR button allows the scanner to resume operating, but at a very slow rate (approximately 2 Hz). This manual scan rate is slow enough to permit the operator to readily stop the scanning action when the scanner has reached his desired channel.

While scanning, the scanner is stopped on a channel if a carrier is being received by the unit. First, the squelch is broken and then the stop-start stage (Q404) starts conducting. When Q404 is conducting, it lowers the voltage available to the emitter of the unijunction (Q406) below its firing point, thus stopping pulse generation. There is a delay in the resumption of scanning action after the carrier is removed. This delay is provided by C403, which is connected to the collector of Q404 when the SCAN-MANUAL button is pushed in (scan mode). The delay permits a short interval of a "stopped clock" so that another signal (carrier) responding to the first signal (for example a mobile station replying to its base station) can come on channel without the unit scanning through all of the other channels.

The three push buttons labeled 1-8, ALL and 9-16 in Model TME-16H/L, or the five push buttons labeled Hi, Lo, Hi/Lo, UHF and ALL in Model TME-16H/L/U, select which group of programming buttons is connected to the register's activate output line. For example, when the 9-16 button is pushed in, only the programming buttons 9 through 16 are connected to the registers so that these channels can be activated. Thus, even though channels 1 and 5 (for example) may be programmed for operation, the enter group of buttons 1 through 8 are actually connected so as to be in the inactive mode regardless whether or not they are pushed in or out. In essence, the group Selector buttons overide the channel programming buttons in regards to activation of a particular channel.

SECTION 2 ALIGNMENT AND TUNING PROCEDURE

2-1 EQUIPMENT REQUIRED

- 2-1-1 FM Signal Generator
- 2-1-2 Oscilloscope
- 2-1-3 AC VTVM
- 2-1-4 Noise Generator (to be used in 2-8 only)
- NOTE: During all steps of alignment, the squelch control should be in the maximum clockwise position (minimum squelch action).

All receivers should be aligned to the channel nearest the center of the frequency range in the band over which they will operate.

Diagrams 3-1, 3-3, and 3-5 show the location of all coils to be adjusted.

Diagram 3-12 shows location of RF boards.

2-2 QUADRATURE DETECTOR ALIGNMENT

NOTE: Omit this section for Model TME-16H/L/U

- 2-2-1 Connect the FM Signal generator to the antenna input jack. Accurately set frequency to the center of the channel being used for alignment. Modulate signal generator with 1000 Hz, 3 KHz deviation.
- 2-2-2 Connect the oscilloscope to test point A, (Junction of Cl26, Cl28, R113). See diagram 3-6.
- 2-2-3 Adjust output of signal generator until all noise in scope pattern just disappears.
- 2-2-4 Adjust L103 for maximum peak to peak amplitude, while maintaining symmetry of the detected signal.

2-3 IF ALIGNMENT

- 2-3-1 Disconnect RF signal generator from the antenna input.
- 2-3-2 Connect AC voltmeter across speaker terminals.
- 2-3-3 Adjust volume control for 0.5 volt reading on AC voltmeter.
- 2-3-4 Peak T102 (bottom core and top core, in that order) for maximum noise (maximum meter reading on AC voltmeter). If circuit is not badly misaligned, the correct point should be within 2 turns of the slugs present position.

- NOTE: Coils will have two peaks; adjust core to peak away from the center of the form.
- 2-3-5 Pre-align quadrature detector by tuning L103 for maximum noise (AC voltmeter). Model TME-16H/L/U only.
- 2-3-6 Adjust volume control for 1 volt noise reading on AC voltmeter.
- 2-3-7 Connect the R.F. signal generator to the antenna input jack of "200" series board. Turn modulation off. Set the generator to the high band crystal frequency that will be used for high band section alignment.
- 2-3-8 Adjust the signal generator output until the voltmeter reads 0.2 volts.
- 2-3-9 Adjust T101 and T201 (in that order) for maximum quieting (lowest meter reading). Adjust signal generator to maintain reading on AC voltmeter between 0.1 and 0.2 volts.
- NOTE: Coils will have two peaks; adjust core of T101 to peak away from center of the coil form, and adjust core of T201 to peak nearest the center of the coil form.
- 2-3-10 Set the generator frequency to the secondary image frequency. This is 910 KHz below the channel frequency. NOTE: some receivers have the second oscillator at 11.155 MHz, in this case the image frequency is 910 above the channel frequency. Check the frequency marked on top of the crystal.
- 2-3-11 Adjust the signal generator output until voltmeter reads .2 volts.
- 2-3-12 Adjust T102 (bottom core), T102 (top core), T101 and T201 (in that order) for maximum quieting degradation (highest meter reading). Adjust signal generator output to maintain voltmeter reading between 0.1 and 0.2 volts. The correct position for the cores should be withing two turns of the position in step No. 4 and 9.

2-4 RF ALIGNMENT ("200" SERIES BOARD)

- 2-4-1 Preset the slugs L201, L202 and L203 out of the outer end of the coil form three turns. Preset L204, L206, L207 and L208 four turns from the outer ends of the coil form.
- 2-4-2 Connect AC voltmeter across speaker terminals.
- 2-4-3 With nothing connected to the antenna input, adjust the volume control until AC voltmeter reads 1.0 volt of noise.

HIGH BAND SECTION

2-4-4 Activate high band channel nearest to center of high band frequencies being used.

- 2-4-5 Connect signal generator to antenna input jack of "200" series R.F. board. Set generator accurately to the frequency of the channel being used. Turn modulation off.
- 2-4-6 Adjust output signal generator until AC voltmeter reads .2 volts.
- 2-4-7 Adjust L206, L207, L208 and L204, in that order, for maximum quieting (lowest meter reading). Adjust signal generator to maintain reading on AC voltmeter between ·1 and ·2 volts. Repeat adjustment until no further improvements can be made.

LOW BAND SECTION

- 2-4-8 Activate Low Band channel nearest to center of low band frequencies being used.
- 2-4-9 Set generator accurately to the center frequency of the channel being used for alignment. Turn modulation off.
- 2-4-10 Adjust output of signal generator until AC voltmeter reads 0.2 volts.
- 2-4-11 Adjust coils L201, L202 and L203 (in that order) for maximum quieting (lowest meter reading). Adjust the signal generator output to maintain voltmeter reading between ·1 and ·2 volts. Repeat adjustments until no further improvement can be made.

2-5 RF ALIGNMENT ("300" SERIES BOARD - TME - 16 H/L)

- 2-5-1 Preset the slugs L301, L302 and L303 out of the outer end of the coil form three turns. Preset L304, L306, L307 and L308 four turns from the outer ends of the coil form.
- 2-5-2 Connect AC voltmeter across speaker ternimals.
- 2-5-3 With nothing connected to the antenna input, adjust the volume control until AC voltmeter reads 1.0 volt of noise.

HIGH BAND SECTION

- 2-5-4 Activate high band channel nearest to center of high band frequencies being used.
- 2-5-5 Connect signal generator to antenna input jack of "300" series RF board. Set generator accurately to the frequency of the channel being used. Turn modulation off.
- 2-5-6 Adjust output signal generator until AC voltmeter reads .2 volts.
- 2-5-7 Adjust T301 for maximum quieting (lowest meter reading). Adjust signal generator output to maintain voltmeter reading between .1 and .2 volts of "300" series RF board.

2-5-8 Adjust L306, L307, L308 and L304, in that order, for maximum quieting (lowest meter reading). Adjust signal generator to maintain reading on AC voltmeter between 1 and 2 volts. Repeat adjustment until no further improvements can be made.

LOW BAND SECTION

- 2-5-9 Activate Low Band channel nearest to center of low band frequencies being used.
- 2-5-10 Set generator accurately to the center frequency of the channel being used for alignment. Turn modulation off.
- 2-5-11 Adjust output of signal generator until AC voltmeter reads 0.2 volts.
- 2-5-12 Adjust coils L301, L302, and L303 (in that order) for maximum quieting (lowest meter reading). Adjust the signal generator output to maintain voltmeter reading between ·1 and ·2 volts. Repeat adjustments until no further improvement can be made.

2-6 RF ALIGNMENT ("300" SERIES BOARD - TME - 16 H/L/U)

- 2-6-1 Connect the R.F. signal generator to the antenna input jack of the "300" series board. Set the generator to the operating crystal frequency.
- 2-6-2 Adjust output of signal generator until AC voltmeter reads 0.2 volts.
- 2-6-3 Pre-Adjust Trimmer Capacitor (C317) so that the silvered halfmoon section is nearest to the rear of the receiver.
- 2-6-4 Adjust T301 for maximum quieting (lowest meter reading).

 Adjust signal generator output to maintain voltmeter reading between ·1 and ·2 volts.
- 2-6-5 Adjust C301 and C302 (trimmer capacitors) in that order, for maximum quieting (lowest meter reading). Adjust signal generator output to maintain voltmeter reading between ·1 and ·2 volts. Repeat adjustments until no further improvements can be made.
- NOTE: Use non-metallic screwdriver for trimmer adjustments.
 - Peaks are very sharp, tune with care. Two peaks can be observed, tune to peak with silver moon section away form I.F. Board.
- 2-6-6 Adjust the core of L303 for maximum quieting (lowest meter reading). Adjust signal generator to maintain reading on AC voltemter between .1 and .2 volts.
- NOTE: To properly adjust L303, C317 must be pre-adjusted as in Step 2-3-11.

- 2-6-7 Adjust C317 counter clockwise with non-metallic screwdriver for maximum quieting (lowest meter reading). Adjust signal generator to maintain reading on AC voltmeter between .1 and .2 volts. Do NOT re-adjust L303 after C317 is adjusted.
- 2-6-8 Re-adjust C301, C302 and C317 (only) for maximum quieting (lowest meter reading). Adjust signal generator output to maintain ·1 and ·2 volts. Repeat adjustments until no further improvements can be made.

2-7 AFC ALIGNMENT (TME-16H/L/U ONLY)

- NOTE: This adjustment requires an accurate 10.7 MHz ±1 KHz oscillator or 455 KHz ±500 Hz oscillator to be used as a reference signal. If none are available, proceed to Step 2-7-5.
- 2-7-1 Pre-align Quadrature Detector by tuning L103 for maximum noise (AC voltmeter reading) at the speaker terminals.
- 2-7-2 With a coupling loop, inject "reference" signal (either 10.7 MHz or 455 KHz) to produce good quieting (more than 30 DB quieting).

 Adjust R326 for reading of 3.8 to 4.0 volts at the collector of Q304.
- 2-7-3 Remove the "reference" signal and have the unit squelched and receiving no signal. The voltage on the collector of Q304 shall be between 3.2 and 4.6 volts. If not, note voltage and proceed to Step 2-7-4. If voltage is between 3.2 and 4.6 volts, AFC Alignment is complete.
- NOTE: Any further adjustments made to L103 and R326 will require AFC to be re-adjusted.
- 2-7-4 Inject "Reference" signal and monitor voltage on collector of Q304, adjust L103 for same voltage as noted in Step 3. Re-adjust R326 for a voltmeter reading of 3.8 to 4.0 volts. Repeat Step 2-4-3.
- NOTE: Do not adjust L103 more than 1/4 turn at a time.
- 2-7-5 If an accurate I.F. signal source is not available, an approximate AFC alignment can be made by adjusting L103 for maximum noise (AC voltmeter reading) at the speaker terminals, and with unit squelched and receiving no signal, adjust R326 for a voltmeter reading of 3.2 to 4.6 on the collector of Q304.
- NOTE: Units equiped with a 10.245 MHz crystal have the jumper in the AFC circuit connected between the base of Q304 and collector of Q306. When a 11.155 MHz crystal is used, the jumper is connected between the base of Q304 and the collector of Q305. If crystal is changed from one frequency to the other, the jumper must be changed.

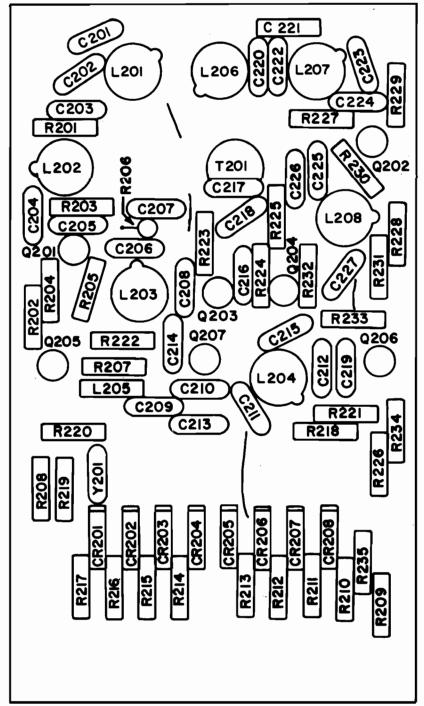
2-8 NOISE BALANCE ADJUSTMENT (TME-16H/L ONLY)

- NOTE: This adjustment may be required only if excessive "ignition noise" is encountered. Usually, the "noise" problem is caused by improper of inadequate noise suppression of the vehicle's ignition system. In Models containing UHF RF Board (TME-16H/L/U), noise balance is achieved through AFC Alignment.
- 2-8-1 Using a "T" connector, connect the FM signal generator and the Noise Generator to the antenna input jack. If a "T" connector is not available, connect the FM generator to the antenna jack and feed in the noise signal by means of a 3 or 4 turn loop coupled to the input coil, L206.
- 2-8-2 Connect the oscilloscope to the junction of Q109's emitter and Q110's collector, or to the speaker terminals.
- 2-8-3 Apply a 3 to 10 microvolt signal, as accurately as can be set to the exact channel frequency (carrier only, no modulation), and adjust the output of the noise generator until spikes are clearly seen in the audio output as viewed on the oscilloscope. The noise spikes will be either mostly positive of negative if an unbalanced condition exists.
- 2-8-4 Tune L103 (quadrature detector coil) until the noise spikes are equally positive and negative in their amplitude. The overall amplitude of these spikes should be much less as a balance is achieved. Usually, only a 1/4 turn, or less, is needed to obtain the proper adjustment for best noise balance. If a proper balance can not be achieved, repeat the IF and RF alignments and then try the noise balance adjustment again.

SECTION 3 DIAGRAMS, VOLTAGE DATA AND SCHEMATICS

- 3-1 RF BOARD PARTS PLACEMENT DIAGRAM (H/L BOARD)
- 3-2 RF BOARD BOTTOM VIEW (H/L BOARD)
- 3-3 RF BOARD PARTS PLACEMENT DIAGRAM (UHF BOARD)
- 3-4 RF BOARD BOTTOM VIEW (UHF BOARD)
- 3-5 IF-AUDIO BOARD PARTS PLACEMENT DIAGRAM
- 3-6 IF-AUDIO BOARD BOTTOM VIEW
- 3-7 SCANNER BOARD PARTS PLACEMENT DIAGRAM
- 3-8 SCANNER BOARD BOTTOM VIEW
- 3-9 SCANNER BOARD (SECONDARY) PARTS PLACEMENT DIAGRAM
- 3-10 SCANNER BOARD (SECONDARY) BOTTOM VIEW
- 3-11 VOLTAGE DATA
- 3-12 CRYSTAL LOCATION DIAGRAMS
- 3-13 BAND PROGRAMMING DIAGRAM
- 3-14 SCHEMATIC (TME 16 H/L)
- 3-15 SCHEMATIC (TME 16 H/L/U)

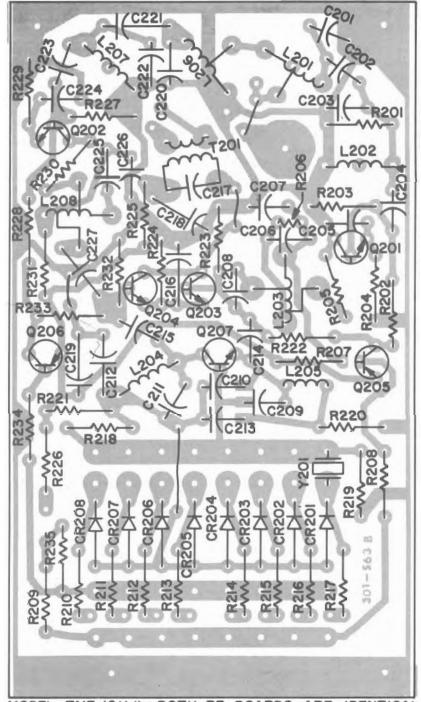
RF BOARD 301-563



MODEL TME-16H/L: BOTH RF BOARDS ARE IDEN-TICAL EXCEPT FOR ONE BEING A "200" SERIES BOARD AND THE OTHER A "300" SERIES BOARD.

3-1 RF BOARD PARTS PLACEMENT DIAGRAM (H/L BOARD)

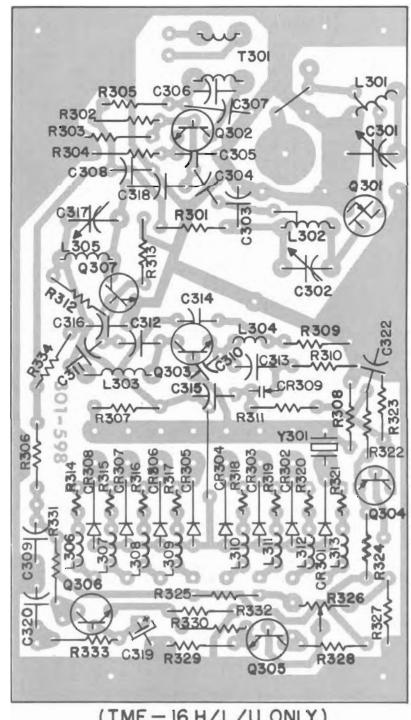
RF BOARD 301-563



MODEL TME-16H/L: BOTH RF BOARDS ARE IDENTICAL EXCEPT FOR ONE BEING A "200" SERIES BOARD AND THE OTHER A "300" SERIES BOARD.

3-2! RF BOARD BOTTOM VIEW (H/L BOARD)

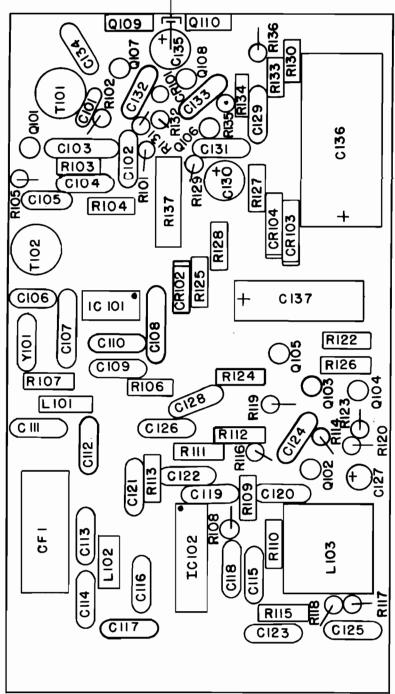
RF BOARD 301-598



(TME - 16 H/L/U ONLY)

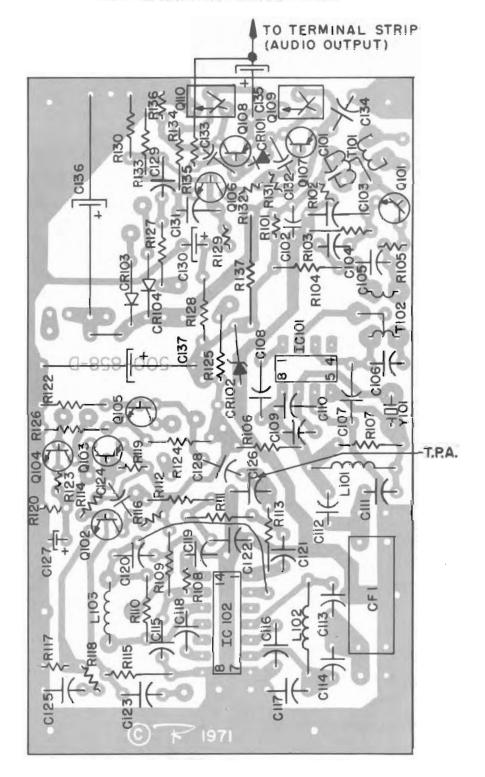
3-4 RF BOARD BOTTOM VIEW (UHF BOARD)

IF BOARD 500-858

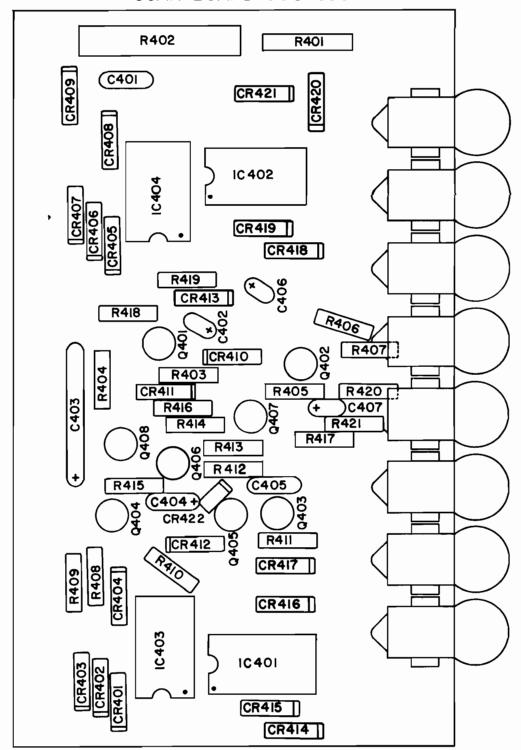


3-5 IF-AUDIO BOARD PARTS PLACEMENT DIAGRAM

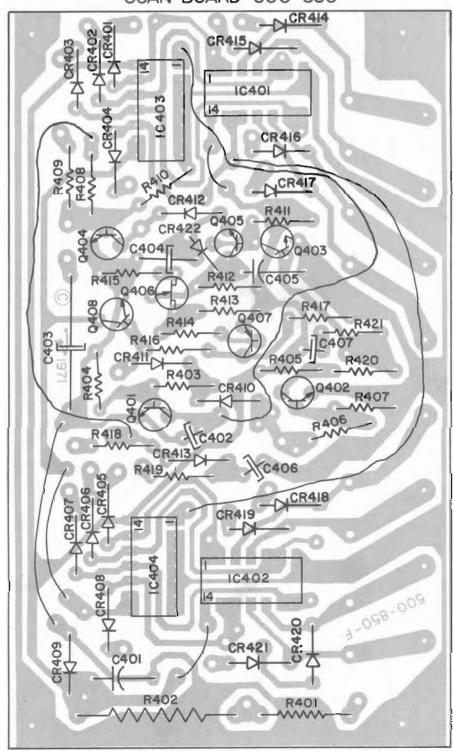
IF BOARD 500-858



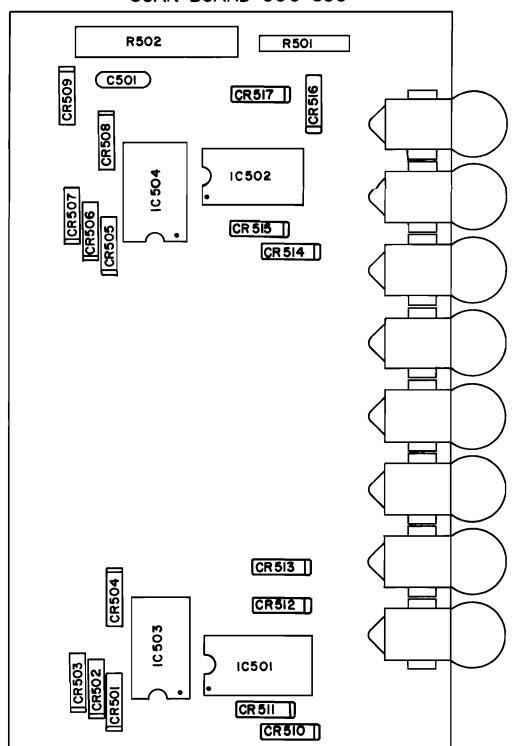
3-6 IF-AUDIO BOARD BOTTOM VIEW



3-7 SCANNER BOARD PARTS PLACEMENT DIAGRAM

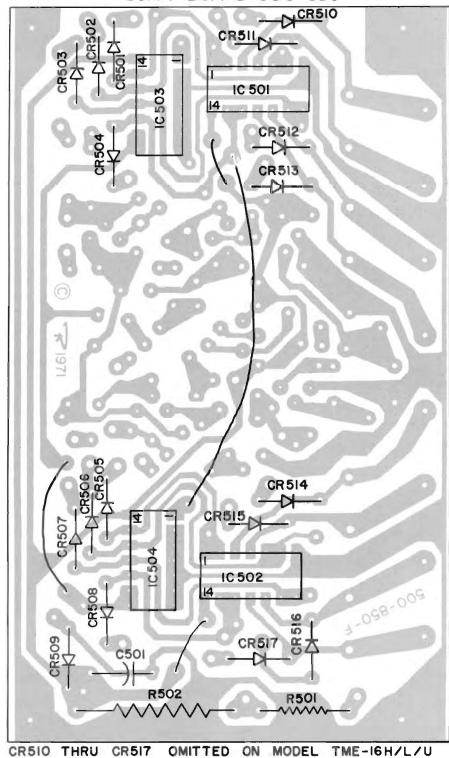


3-8 SCANNER BOARD BOTTOM VIEW



CR510 THRU CR517 OMITTED ON MODEL TME-16H/L/U.

3-9 SCANNER BOARD (SECONDARY) PARTS PLACEMENT DIAGRAM



3-10 SCANNER BOARD (SECONDARY) BOTTOM VIEW

SECTION 3

3-11 VOLTAGE DATA

NOTE: All voltages are nominal and are measured with a VTVM. SCAN indicates the unit is scanning. MAN indicates the unit is not scanning and is stopped at channel 1. A "P" beside a voltage indicates that the meter reading is pulsating (fluctuating) because the scanner section of the unit is operating.

VOLTAGE DATA – TRANSISTORS:

	TRANSISTOR	EMITTER (Source)	BASE (Gate)	COLLECTOR (Drain)
RF Board				
No. 301-563	Q201	3.1 0	3.8 0	7.0 Low Band Activated 7.6 High Band Activated
Note: Model TME-16H/L	Q202	0 3.1	0 3.8	7.6 Low Band Activated 7.0 High Band Activated
has "300"	Q203	1.6	2.3	7.1 Low Band Activated
Series RF Board	0204	1.6	$0 \\ 0$	7.1 High Band Activated
voltages identical to "200" Series	Q204	1.6 1.6	2.3	7.1 Low Band Activated7.1 High Band Activated
RF Board voltages	Q205	7.8	7.4	7.6 Low Band Activated
rei Boura vortages	Q203	7.8	11.0	0v High Band Activated
	Q206	7.8	11.0	0 Low Band Activated
		7.8	7.0	7.6 High Band Activated
	Q207	3.4	4.1	7.0
RF Board				
No. 301-598	Q301(FET)	0	0	5.5
	Q302	1.5	2.2	6.8
NOTE: Model	Q303	.25	3.1	6.8
TME-16H/L/U	Q304	7.8	7.2	3.0-5.0
only.	Q305	2.9	3.6	7.4
	Q306	2.9	3.6	7.2
IE D	Q307	0	.2	6.8
IF Board	0101	2.2	2.0	5.0
No. 500-858	Q101	2.3	3.0	5.8
	Q102	1.0	1.7	4.8
	Q103 (PNP)	8.2	8.2	0 (unsquelched)
		8.2	8.2	1.0 (squelched)
	0104	8.2	8.2 0	1.5 Min. (tight squelch)
	Q104	0	.80	7.2 (unsquelched) .30 (squelched)
		0	.80 .80	•
	Q105	1.4	.80 1.9	.10 (tight squelch) 5.1 (unsquelched)
	Q103	1.4	.10	•
	Q106	0.7	1.3	8.2 (tight squelch) 12.4
	Q100 Q107 (PNP)	13.8	13.1	7.2
	Q107 (PNP) Q108 (PNP)	6.9	6.6	.10
	Q108 (FNF) Q109	6.9	7.2	13.8
	Q109 Q110	0.9	.10	6.9
C D 1	~			
Scan Board	Q401	0	.70	.10 (SCAN)
N= 500.050	0402	0	.70	0 (MAN)
No. 500-850	Q402	0	.70	.10

3-11 VOLTAGE DATA (CONTINUED)

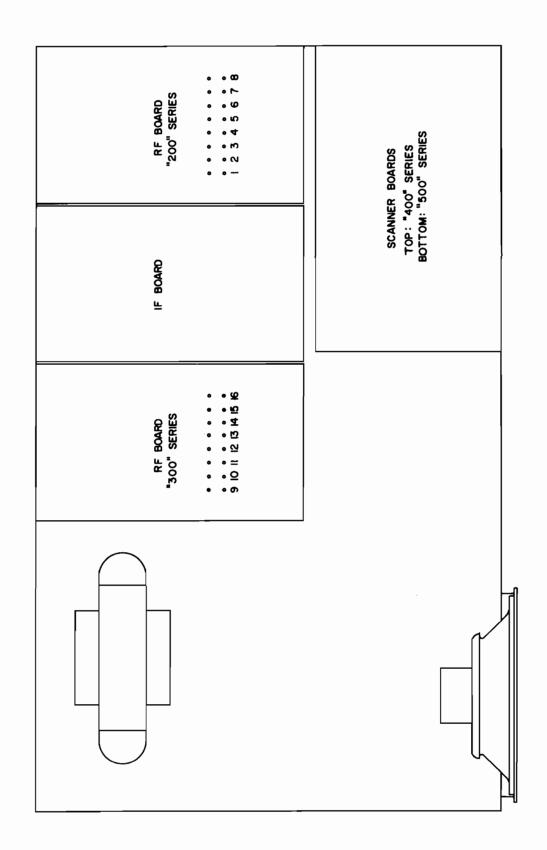
TRANSISTOR	EMITTER (Source)	BASE (Gate)	COLLECTOR (Drain)
Q403	0	.10	3.6 (SCAN)
	0	.10	1.2 (MAN)
Q404	0	.10	2.8 (SCAN)
	0	.70	0.2 (MAN)
Q405	3.1	3.6	3.2 (SCAN)
	0.7	1.2	0.7 (MAN)
Q407 (PNP)	5.1	4.5	.20 (SCAN)
	5.1	4. 6	.10 (MAN)
Q408	0	.10	1.5
1	Base 1	Emitter	Base 2
Q406	.20	3.2	4.6 (SCAN)
(unijunction)	.20	0.7	4.6 (MAN)

3-11 VOLTAGE DATA (CONTINUED)

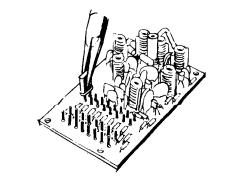
VOLTAGE DATA – INTEGRATED CIRCUITS

A "P" beside a voltage indicates that the meter reading is pulsating (fluctuating) because the scanner section of the unit is operating. MAN indicates the unit is not scanning and is at channel 1 (M401 is lighted). NOTE

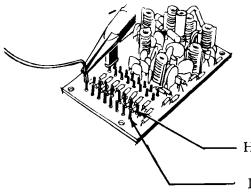
			(Scan) (Man)	(Scan) (Man)	(Scan) (Man)	(Scan) (Man)	(Scan) (Man)	(Scan) (Man)	(Scan) (Man)	(Scan)
14	I	5.0	5.1	5.1	5.1	5.1	5.1	5.1	5.1	5.1
13	I	7.6	.7P 0.2	.7P 0.2	.7P 3.3	.7P 0.2	.7P 0.2	.7P 0.2	.7P 0.2	.7P 0.2
12	ļ	3.5	.7P 0.2	.7P 0.2	.7P 0.2	.7P 0.2	.7P 0.2	.7P 0.2	.7P 0.2	.7P 0.2
11	1	2.9	9P 10.8	9P 10.8	.7P 0.2	.7P 0.2	9P 10.8	9P 10.8	.7P 0.2	.7P 0.2
10	I	1.4			.7P 0.2	_			_	_
6	I	0.2			1.5		_	_		
∞	7.8	0	.7P 0.2	.7P 0.2	1.5	1.5	.7P 0.2	.7P 0.2	1.5	1.5
7	4.2	0	0 0	0	0	0 0	0 0	0 0	0	0 0
		1.3	.7P 0.2	.7P 0.2	0	0	.7P 0.2	.7P 0.2	0	0
	7.8	1.3	•	.7P 0.2	0	0 0	.7P 0.2	.7P 0.2	0	0 0
4	4.2	1.3		9P 10.8				9P 10.8		0 0
8	0.7	0	9P 0.5	9P 10.8	0					0 0
C1	0.7	3.5	.7P 3.3	.7P 0.2	0	0 0	.7P 0.2	.7P 0.2	0	0 0
_	4.2	4.0	.7P	.7P 0.2	0.1	.7P 0.2	.7P 0.2	.7P 0.2	.7P 0.2	.7P 0.2
IC No.	IC 101	IC 102	IC 401	IC 402	IC 403	IC 404	IC 501	IC 502	IC 503	IC 504
	IF Board	200-828	Scan Board 500-850				Scan Board Secondary	0.00-000		



3-12 CRYSTAL LOCATION DIAGRAM



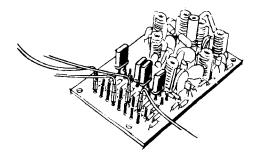
Insert crystal for high or low band frequency of your choice



Connect lead to corresponding high or low band terminal programmer

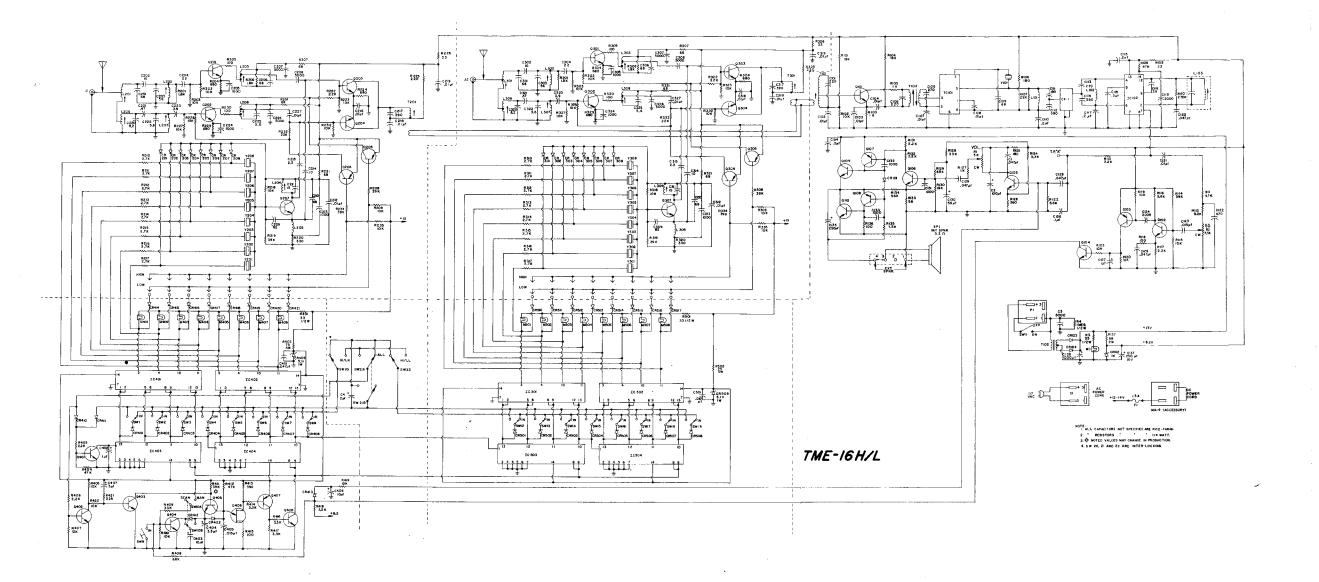
- HIGH BAND

LOW BAND

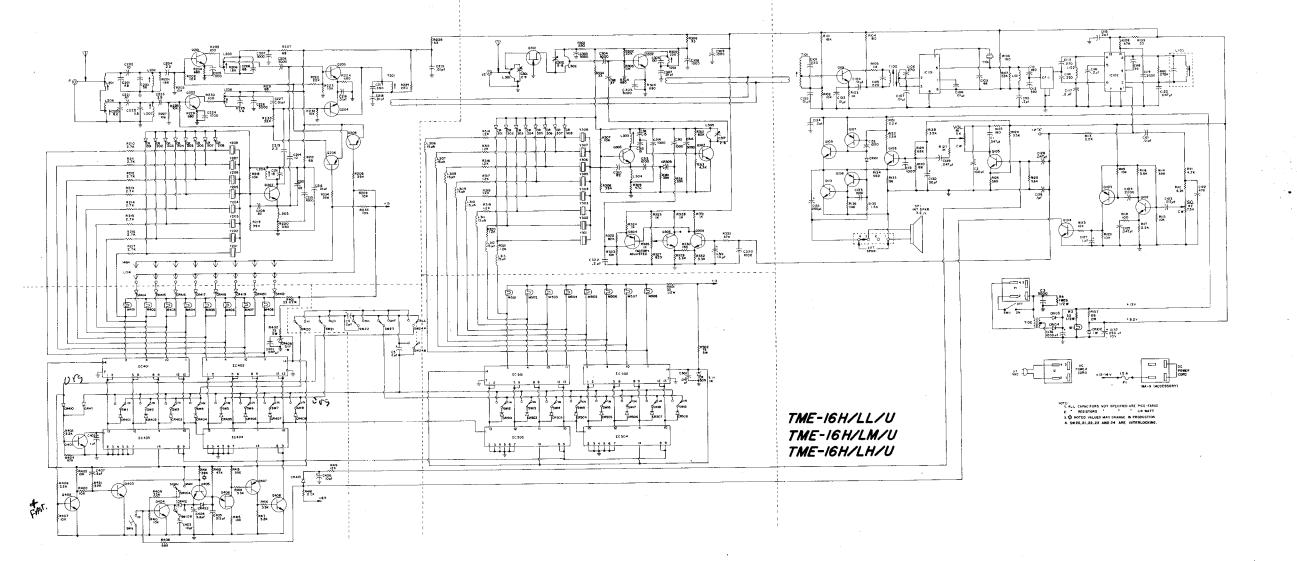


Repeat procedure for each channel in sequence of your choice

3-13 BAND PROGRAMMING DIAGRAM



3-14 SCHEMATIC (TME - 16 H/L)



3-15 SCHEMATIC (TME - 16 H/L/U)

SECTION 4 PARTS LIST 4-1 RF BOARD (H/L) 301-563

NOTE: In Model TME-16H/L both RF Boards are identical except for one being a "200" series board and the other a "300" series board.

Item No	. Description	Part No.	Item No	Description	Part No.
	RESISTORS		C208	.005mf, +80%-20%, 500VZ5U (DISC)	RMC-Type SM
	NESISTONS		C209	82pf, 5%, 50V (MICA)	DM-10 or Equ
R201	1.8K, 10%, ½W		C210	68pf, 5% 50V (MICA)	DM-10 or Equ
R202	10K, 10%, ¼W		C211	15pf, 10% NPO (DISC)	RMC-Type CG
R203	10K, 10%, ¼W		C212	.01mf, +80%-20%, 500VZ5U (DISC)	RMC-Type BG
R204	680ohm, 10%, ¼W		C213	.001mf, +80%-20%, 500V (DISC)	RMC-Type BG
H205	100ohm, 10%, 14W		C214	10pf, 10% NPO (DISC)	RMC-Type CC
R206	1.8K, 10%, ¼W		C215	2.2pf, 10% NPO (DISC)	RMC-Type CG
R207	68ohm, 10%, ¼W		C216	.01mf, +80%-20%, 500VZ5U (DISC)	RMC-Type BG
R208	39K, 10%, ¼W		C217	390pf, 5% 50V (MICA)	DM-10 or Equ
R209	10K, 10%, ¼W		C218	.01mf, +80%-20%, 500VZ5U (DISC)	RMC-Type BG
R210	2.7K, 10%, ¼W		C219	.01mf, +80%-20%, 500VZ5U (DISC)	RMC-Type BG
R211	2.7K, 10%, ¼W		C220	8.2pf, 10% NPO (DISC)	RMC-Type CG
R212	2.7K, 10%, ¼W		C221	.47pf, 10% (composition)	
R213	2.7K, 10%, ¼W		C222	5.6pf, 10% NPO (DISC)	RMC-Type CG
R214	2.7K, 10%, ¼W		C223	3.9pf, 10% NPO (DISC)	RMC-Type CG
R215	2.7K, 10%, ¼W		C224	.001, +80%-20%, 500VZ5U (DISC)	RMC-Type BG
R216	2.7K, 10%, ¼W		C225	5.6pf, 10% NPO (DISC)	RMC-Type CG
R217	2.7K, 10%, ¼W		C226	.005mf, +80%-20%, 500VZ5U (DISC)	RMC-Type SM
R218	10K, 10%, ¼W		C227	.01MF, +80%-20%, 500VZ5U (DISC)	RMC-Type BG
R219	39K, 10%, ¼W				
R220	330ohm, 10%, ¼W				
R221	68ohm, 10%, ¼W			COILS	
R222	22K, 10%, ¼W			- 0 - 0 - 0 - 0	
R223	10K, 10%, ¼W		L201	Coil, Ant. (YEL)	301-520-4
R224	680ohm, 10%, ¼W		L202	Coil, RF Input (GRN)	301-520-5
R225	220ohm, 10%, ¼W		L203	Coil, RF Output (BLU)	301-520-6
R226	33ohm, 10%, ¼W	_	L204	Coil, RF Inj. (WHT)	301-520-9
R227	10K, 10%, ¼W		L205	Coil, Osc.	102-369
R228	10K, 10%, ¼W		L206	Coil, Ant (BRN)	301-520-1
R229	680ohm, 10%, ¼W	~	L207	Coil R.F. Input (RED)	301-520-2
R230	100ahm, 10%, ¼W		L208	Coil RF Output (ORG)	301-520-3
R231	68ohm, 10%, ¼W		T201	Coil Mixer Output	102-405
R232	10K, 10%, ¼W				
R233	22K, 10%, ¼W			TRANSISTORS	
R234	39K, 10%, ¼W			TRANSISTORS	
R235	10K, 10%, ¼W		Q201	Silicon NPN, 2N5222	SPS-1473 RT
			Q2 0 2	Silicon NPN, 2N5222	SPS-1473 RT
	CAPACITORS		Q203	Silicon NPN, 2N5222	SPS-1473 RT
2021	00-4 504 (04.00)	DM 10 5	Q204	Silicon NPN, 2N5222	SPS-1473 RT
C201	68pt, 5%, 50V (MICA)	DM-10 or Equiv.	Q205	Silicon PNP, 2N5227	SPS-1539 WT
C202	10pf, 10% NPO (DISC)	RMC-Type CG	Q206	Silicon PNP, 2N5227	SPS-1539 WT
C203	56pf, 5% 50V (MICA)	DM-10 or Equiv.	Q207	Silicon NPN, 2N5230 (Low Beta)	SM-4304-S
C204	22pf, 10% NPO (DISC)	RMC-Type CG			
C205	.001mf, +80%-20%, 500VZ5U(DISC)	RMC-Type BG		Note: RT=red top, WT=white top	
C206	68pf, 5% 50V (MICA)	DM-10 or Equiv.			
C207	.005mf, +80%-20%, 500VZ5U (DISC)	RMC-Type SM			

Item N	lo. Descrip	tion	Part No.
	DIO	DES	
CR201	Germanium-Junction S	ignal	102-339
CR202	Germanium-Junction S	ignal	102-339
CR203	Germanium-Junction S	ignal	102-339
CR204	Germanium-Junction S	ignal	102-339
CR205	Germanium-Junction S	ignal	102-339
CR206	Germanium-Junction S	ignal	102-339
CR207	Germanium-Junction S	ignal	102-339
CR208	Germanium-Junction S	ignal	102-339

4-2 RF BOARD (UHF) 301-598 TME - 16 H/L/U ONLY

Item No	Description	Part No.	Item No	Description	Part No.
	RESISTORS		C306	150pf, 5% 50V (Mica)	DM-10 or Equi
			C307	.01MF, +80%-20% 500V, Z5U (Disc)	RMC-Type BG
R301	220 ohm, 10%, ¼W		C308	.005MF, +80%-20% 500V, Z5U (Disc.)	RMC-Type SM
R302	22K, 10%, ¼W		C309	.001MF, +80%-20% 500V, Z5U (Disc.)	RMC-Type BG
R303	10K, 10%, ¼W		C31 0	82pf, 5% 50V (Mica)	DM-10 or equiv
R304	680 ohm, 10%, ¼W		C311	15pf, 10%, NPO (Disc.)	RMC-Type CG
F305	220 onm, 10%, %W		C312	15pf, 10% NPO (Disc.)	RMC-Type CG
R306	33 ohm, 10%, ¼W		C313	.001MF, +80%-20% 500V, Z5U (Disc.)	RMC-Type BG
R307	10K, 10%, ¼W		C314	.001MF, +80%-20% 500V, Z5U (Disc.)	RMC-Type BG
R308	38K, 10%, ¼W		C315	.001MF, +80%-20% 500V, Z5U (Disc.)	RMC-Type BG
R309	470 ohm, 10%, ¼W		C316	.005MF, +80-20% 500V, Z5U (Disc)	RMC-Type SM
R310	39K, 10%, ¼W		C317	2-8pf, NPO, Trimmer	10S Triko 22
R311	39K, 10%, ¼W		C318	.47pf, 10% (Composition)	
R312	82K, 10%, ¼W		C319	1.0mf 85°C 50V (Electrolytic)	
R313	4.7K, 10%, ¼W		C320	.001MF, +80%-20% 500V, Z5U (Disc.)	RMC-Type BG
R314	1.2K, 10%, ¼W		C322	.2 MF, +80%-20% 12V (Disc.)	Murata
R315	1.2K, 10%, ¼W			, , , , , , , , , , , , , , , , , , , ,	Type BC-12
R316	1.2K, 10%, ¼W				
R317	1.2K, 10%, ¼W			COILS	
R318	1.2K, 10%, ¼W				
R319	1.2K, 10%, ¼W		L301	Coil, RF Input	301-600-1
R320	1.2K, 10%, ¼W		L302	Coil, RF Output	301-600-2
R321	1.2K, 10%, ¼W		L303	Coil, RF (Red)	301-520-2
R322	82K, 10%, ¼W		L304	Coil, RF Osc.	102-369
R323	10K, 10%, ¼W		L305	Coil, RF Osc.	301-600-3
R324	1K, 10%, ¼W		L306	Choke, 15uh	
R325	1K, 10%, ¼W		L307	Choke, 15uh	
R326	Trimmer 1K, 30% (Stand Up)	X201R102B	L308	Choke, 15uh	
R327	820 ohm, 10%, ¼W		L309	Choke, 15uh	
R328	1K, 10%, ¼W		L310	Choke, 15uh	
R329	3.3K, 10%, ¼W		L311	Choke, 15uh	
R330	150 ohm, 10%, ¼W		L312	Choke 15uh	
R332	1K, 10%, ¼W		L313	Choke, 15uh	
R332	3.3K, 10%, ¼W		T301	Coil, Mixer	301-619
R333	47K, 10%, ¼W			TD ANDIOTOD	
R324	33 ohm, 10%, ¼W			TRANSISTOR	
	CAPACITORS		Q301	Silicon, N-Channel FET	2N5245
	OAI AOI I OII 3		Q302	Silicon NPN, 2N5222	SPS-1473 (RT)
C301	2-8pf, NPO, Trimmer	10S-Triko 22	Q303	Silicon NPN (Low Beta) 2N5130	SM-4304-S
C302	2-8pf, NPO, Trimmer	10S-Triko 22	Q304	Silicon PNP, 2N5227	SPS-1539 (WT)
C303	.005MF, +80%-20% 500V, Z5U (Disc.)	RMC-Type SM	Q305	Silicon NPN, MPS-5172	SPS-952
C304	.005MF, +80%-20% 500V, Z5U (Disc.)	RMC-Type SM	Q306	Silicon NPN, MPS-5172	SPS-952
C305	.005MF, +80%-20% 500V, Z5U (Disc.)	RMC-Type SM	Q307	Silicon NPN, 2N5222 T = Red Top, WT = White Top	SPS-1473 (RT)

Item No	o. Description	Part No.
	DIODES	
CR301	Germanium-Junction, Signal	102-339
CR302	Germanium-Junction, Signal	102-339
CR303	Germanium-Junction, Signal	102-339
CR304	Germanium-Junction, Signal	102-339
CR305	Germanium-Junction, Signal	102-339
CR306	Germanium-Junction, Signal	102-339
CR307	Germanium-Junction, Signal	102-339
CR308	Germanium-Junction, Signal	102-339
CR309	Silicon, Varactor	Motorola MV2209
	MISCELLANEOUS	
	Sheild Assembly	301-602

4-3 IF-AUDIO BOARD 500-858

Item No.	Description	Part No.	Item No	Description	Part No.
	RESISTORS		C106	27pf, 5% 50V (Mica)	DM-10 or equiv
	NESISTONS		C107	.01mf+80%-20% 500V Z5U (Disc.)	RMC-Type BG
	18K, 10%, ¼W		C108	.01mf+80%-20% 500V Z5U (Disc.)	RMC-Type BG
3102	10K, 10%, ¼W		C109	68pf, 5% 50V (Mica)	DM-10 or equiv
R103	1K, 10%, ¼W		C110	.2mf, +80%-20% 12V (Disc.)	Murata Type B
R104	180 ohm, 10%, ¼W		C111	180pf, 5% 50V (Mica)	DM-10 or equiv
	1K, 10%, ¼W W		C112	390pf, 5% 50V (Mica)	DM-10 or equiv
	180 ahm. 10%. ¼W		C113	270pf, 5% 50V (Mica)	DM-10 pr aquiv
	22K, 10%, ¼W		C114	250pf, 5% 50V (Mica)	DM-10 or equiv
	47K, 10%, ¼W		C115	.2mf, +80%-20% 12V (Disc)	Murata Type B
	33 ohm, 10%, ¼W		C116	.2mf, +80%-20% 12V (Disc.)	Murata Type B
	270K, 10%, ¼W		C117	.2mf, +80%-20% 12V (Disc.)	Murata Type B
	4.7K, 10%, ¼W		C118	39pf, 10% NPO (Disc.)	RMC-Type CG
	8.2K, 10%, ¼W		C119	.002mf, 20% 500V Z5U (Disc.)	RMC-Type JG
R113	2.2K, 10%, ¼W		C120	.047mf, 10% 100V (Mylar Film)	
	39K, 10%, ¼W		C121	.01mf, 10% 100V (Mylar Film)	
R115	10K, 10%, ¼W		C122	470pf, 20% 500V Z5F (Disc.)	RMC-Type JG
R116	5.6, 10%, ¼W		C 123	.015mf, 10% 100V (Mylar Film)	
R117	2.2K, 10%, ¼W		C124	.002mf, 20% 500V Z5U (Disc.)	RMC-Type JG
1118	100ohm, 10%, ¼W		C125	.047mf, 10% 100V (Mylar Film)	
1119	10K, 10%, ¼W		C126	.1mf, 20% 12V (Disc.)	Murata Type B
R120	10K, 10%, ¼W		C127	1mf, 85°C 50V (Electrolytic)	
R122	5.6K, 10%, ¼W		C128	.047mf, 10% 100V (Mylar Film)	
1123	10K, 10%, ¼W		C129	.047mf, 10% 100V (Mylar Film)	
R124	3.3K, 10%, ¼W		C130	50mf, 85°C 10V (Electrolytic)	
R125	180 ohm, 10%, ¼W		C131	.001+80%-20% 500V Z5U (Disc.)	RMC-Type BG
1126	560 ohm, 10%, ¼W		C132	.001+80%-20% 500V Z5U (Dsic.)	RMC-Type BG
3127	1K, 10%, ¼W		C133	.001+80%-20% 500V Z5U (Disc.)	RMC-Type BG
1128	33K, 10%, ¼W		C134	.2mf, +80%-20% 12V (Disc.)	Murata Type B(
3129	68K, 10%, ¼W		C135	250mf, 85°C 16V (Electrolytic)	
R130	18K, 10%, ¼W		C136	1000mf, 85°C 16V (Electrolytic)	
₹131	2.2K, 10%, ¼W		C137	250mf, 85°C 10V (Electrolytic)	
R132	2.2K, 10%, ¼W				
R133	56 ohm, 10%, ¼W			COILS	
R134	560 ohm, 10%, ¼W		T101	Coil, 10.7 MHz Input	102-507
R135	1.5K, 10%, ¼W		T102	Coil, 10.7 MHz Output	301-730
136	100 ohm, 10%, ¼W		L101	Choke, 820uh	
R137	68 ohm, 10% 2W (Wire Wound) IRC-T	ype BWH	L101	Chike, 820uh	ES-2228 ES-2228
	CAPACITORS		, L103	Coil, Quadrature	301-517
0101	220pf, 5% 50V (Mica)	DM-10 or equiv.		INTEGRATED CIRCUITS	
C102	.01mf, 10% 100V (Mylar Film)				
2103	.01mf, +80%-20% 500V Z5U (Disc.)	RMC-Type BG	IC101	Integrated Circuit	301-679-1
2104	.01mf, 10%, 100V (Mylar Film)		IC102	Integrated Circuit, MC-1357P	301-576-3
0105	220pf, 5% 50V (Mica)	DM-10 or equiv.			

Item No	. Description	Part No.
	DIODES	
C R101	Diode, Silicon, 1N4148	102-412
CR102	Diode, Zener, 8.2V 5% 1W.	IN4738A
CF103	Diode, Rectifier	1N4002
CR104	Diode, Rectifier	1N4002
	FILTER	
CF-1	455KHz Ceramic Filter (TME-16	H/L/U only) 301-724
CF-1	455KHz Ceramic Filter (TME-16	H/L only) 301-723
	CRYSTAL	
Y101	10.245 MHz or	301-516-1
	11.155 MHz	301-516-2
	TRANSISTORS	
Q101	Siticon NPN, MPS 5172	SPS-952
Q102	Silicon NPN, MPS 5172	SPS-952
Q103	Silicon PNP, 2N5227	SPS-1539 (WT
Q104	Silicon NPN, MPS 5172	SPS-952
Q105	Silicon NPN, MPS 5172	SPS-952
Q106	Silicon NPN, MPS 5172	SPS-952
Q107	Silicon PNP	MPS-A55
Q108	Silicon PNP	MPS-A55
Q109	Silicon NPN, AF Power	MJE-521
Q110	Silicon NPN, AF Power	MJE-521
NOTE: W	/T=White Top	

4-4 SCANNER BOARD 500-850 (PRIMARY BOARD)

Item No.	. Description	Part No.	Item No	. Description	Part No.
	RESISTORS		Q406	PN Silicon, Unijunction	2N4871
D404			Q407	PNP Silicon, 2N227	SPS-1539 (
R401	33ohms, 10%, ¼W		Q408	NPN Silicon, General Purpose, MPS517	72 SPS-952
R402	75 ohms, 10%, 5 W Wirewound		NOTE:	WT - White Top	
R403	2.2K, 10%, ¼W			D.O	
	47K, 10%, ¼W			DIODES	
R405	10K, 10%, ¼W		CR401	Silicon, Signal, IN4148	102-412
	2.2K, 10%, ¼W		CR402	Silicon, Signal, IN4148	102-412
R407	10K, 10%, ¼W		CR503	Silicon, Signal IN4148	102-412
	68K, 10%, ¼W		CR404	Silicon, Signal, IN4148	102-412
	33K, 10%, ¼W		CR406	Silicon, Signal, IN4148	102-412
	22K, 10%, ¼W		CR407	Silicon, Signal, IN4148	102-412
	39K, 10%, ¼W		CR409	Silicon, Zener, 5.1V, 5%, 1W	IN4733A
	47K, 10%, ¼W		CR410	Silicon, Signal, IN4148	102-412
	390 ohms, 10%, ¼W		CR411	Silicon, Signal, IN4148	102-412
	3.3K, 10%, ¼W		CR413	Silicon, Signal, IN4148	102-412
R415	100 ohms, 10%, ¼W		CR414	Silicon, Signal, IN4148	102-412
	3.3K, 10%, ¼W		CR415	Silicon, Signal, IN4148	102-412
	3.3K, 10%, ¼W		CR416	Silicon, Signal, IN4148	102-412
	2.2K, 10%, ¼W		CR417	Silicon, Signal, IN4148	102-412
	12K, 10%, ¼W		CR418	Silicon, Signal, IN4148	102-412
R420	10K, 10%, ¼W		CR419	Silicon, Signal, IN4148	102-412
R421	22K, 10%, ¼W		CR420	Silicon, Signal, IN4148	102-412
	CARACITORS		CR421	Silicon, Signal, IN4148	102-412
	CAPACITORS		CR422	Silicon, Signal, IN4148	102-412
2401	.047mf, 20%, 100V (Mular Film)	•			
2402	1mf, 80°C. 25V (Electrolytic)			LAMPS	
2403	10mf, 85°C. 25V (Electrolytic)		M401	Incandescent, 14.4V, 120 MA.	No. 53
2404	3.3mf, 10%, 16V Tant. (Electrolytic) TA	AG43212-14133	M402	Incandescent, 14.4V, 120 MA.	No. 53
C405	.015mf, 20%, 100V (Mylar Film)		M403	Incandescent, 14.4V, 120 MA.	No. 53
C406	10 mf, 85°C. 25V (Electrolytic)		M404	Incandescent, 14.4V, 120 MA.	No. 53
C407	5mf, 85°C. 10V (Electrolytic)		M405	Incandescent, 14.4V, 120 MA.	No. 53
			M406	Incandescent, 14.4V, 120 MA.	No. 53
	INTEGRATED CIRCUITS		M407	Incandescent, 14.4V, 120 MA.	No. 53
C401	Power NAND Gate	301-576-2	M408	Incandescent, 14.4V, 120 MA.	No. 53
	Power NAND Gate	301-576-2		•	
	4-Bit Shift Register	301-576-6			
	4-Bit Shift Register	301-576-6			
0404	•	301-370-0	4		
	TRANSISTORS	CDC 050	•		
	NPN Silicon, General Purpose, MPS5172				
	NPN Silicon, General Purpose, MPS5172				
	NPN Silicon, General Purpose, MPS5172				
	NPN Silicon, General Purpose, MPS5172				
2405	NPN Silicon, General Purpose, MPS5172	SPS-952			

4-5 SCANNER BOARD 500-850 (SECONDARY BOARD)

Item No	. Description	Part No.	Item No	. Description	Part No
			M503	Incandescent, 14.4V, 120 MA.	No. 53
	RESISTORS		M504	Incandescent, 14.4V, 120 MA.	No. 53
R501	33 ohms, 10%, ¼W		M505	Incandescent, 14.4V, 120 MA.	No. 53
R502	75 ohms, 5%, 5W Wirewound		M506	Incandescent, 14.4V, 120 MA.	No. 53
	CAPACITORS		M507	Incandescent, 14.4V, 120 MA.	No. 53
	CAPACITORS		M508	Incandescent, 14.4V, 120 MA.	No. 53
C501	.047 mf, 20%, 100V (Mylar Film)				
	INTEGRATED CIRCUIT	s			
IC501	Power NAND Gate	301-576-2			
IC502	Power NAND Gate	301-576-2			
IC503	4-Bit Shift Register	301-576-6			
IC504	4-Bit Shift Register	301-576-6			
	DIODES				
CR501	Silicon, Signal, IN4148	102-412			
CR502	Silicon, Signal, IN4148	102-412			
CR503	Silicon, Signal, IN4148	102-412			
CR504	Silicon, Signal, IN4148	102-412			
CR505	Silicon, Signal, IN4148	102-412			
CR506	Silicon, Signal, IN4148	102-412			
CR507	Silicon, Signal, IN4148	102-412			
CR508	Silicon, Signal, IN4148	102-412			
CR509	Silicon, Zener, 5.1V, 5%, 1W	IN4733A			
CR510	Silicon, Signal, IN4148 (TME-16H/L only)				
		102-412			
CR511	Silicon, Signal, IN4148 (TME-16H	/L only)			
		102-412			
CR512	Silicon, Signal, IN4148 (TME-16H)	L only)			
		102-412			
CR513	Silicon, Signal, IN4148 (TME-16H	/L only)			
		102-412			
CR514	Silicon, Signal, IN4148 (TME-16H)	(L only)			
		102-412			
CR 5 15	Silicon, Signal, IN4148 (TME-16H)	(L only)			
		102-412			
CR516	Silicon, Signal, IN4148 (TME-16H)	L only)			
		102-412			
CR517	Silicon, Signal, IN4148 (TME-16H)	L only)	À,		
		102-412			

M501

M502

LAMPS

No. 53

No. 53

Incandescent, 14.4V, 120 MA.

Incancescent, 14.4V, 120 MA.

4-6 CHASSIS ASSEMBLY

Item No	. Description	Part No.
	ELECTRICAL COMPONENTS	
R1	5K, Volume Control	Stackpole R72-00691
R2	7.5K, Squelch Control	Stackpole R72-00692
R3	33 ohms, 10%, ¼W	
R4	1 Meg, 10%, 112W	
C1	.047mf, 10%, 100V (Mylar Film)	
C2	250mf, 85°C 16V (Electrolytic)	
C3	.005mf, +80%-20% 1400 Z5U (Disc.)	RMC-Type U
C4	2mf, 85°C, 50V (Electrolytic)	
T1	Transformer, Power	301-699
M1	Lamp, No. 53	
Y200	See Section 1-2	
Y300	See Section 1-2	
SW1-8,	1P2T, 8 Stations on Single Frame, P-P	UID500-874-3
SW12-19	-	Prom. 301-551-3
SW-11	1P2T, Push-push (UL)	UID 500-874-6
		Prom. 301-551-7
SW9-10	2P2T	UID 500-874-19
		Prom. 301-551-20
SW20-22	2P2T (TME-16H/Lonly)	UID 500-874-13
		Prom. 301-551-14
SW20-24	(TME-16H/L/U only)	UID 500-874-12
	•	Prom. 301-551-6
Ant1	Telescoping Antenna (UHF)	1201-0000-003
Ant1	Telescoping Antenna (H/L)	1201-0000-002
Spk1	Speaker, 3.2 ohm, 3½" Square Assembly	301-793
J1	Antenna, Connector	Cinch 201-24-01-002
P1	Connector, Chassis, Power	Beauchaine
	, ,	P-3304-AB
S1	Connector, Cable, Power	Beauchaine
	, == ,	S-3304-FHT
	AC Power Cord Assembly	MA-1
	Cable, Coaxial 50ohm, Teflon	RG-188/U
	MECHANICAL COMPONENTS	
		202.202
	Panel, Front (TME-16H/L)	600-330
	Panel, Front (TME-16H/L/U)	600-307
	Panel, Back	301-674
	Knob, Volume and Squelch	Plasticware
		301-670
	Lens, Green, Power Indicator	1759
	Lens, Red, Channel Lamps	102-353
	Socket, Lamp (Power)	300-269-4
	Socket, Pins, Crystal	T35-362

Item No.	Description	Part No.
Terminal Board, 4	301-079-14	
Foot, Rubber	Lavelle 705f	
Cabinet/Wrap Ass	600-311	
Manual, Owner's	IS-10-324-1	
Manual, Owner's	IS-10-324-2	
Manual Service (\$5.00 Prepaid)	SM-10-324-1